NSN 5962-00-225-3745

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-225-3745 **Body Length:** 0.800 inches **Body Width:** 0.265 inches **Body Height:** 0.160 inches **Maximum Power Dissipation Rating:** 400.0 milliwatts **Operating Tempurature Range:** -25.0 to 70.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius **Features Provided:** Electrostatic sensitive and monolithic and hermetically sealed **Inclosure Material:** Ceramic or glass or metal **Inclosure Configuration:** Dual-in-line **Output Logic Form:** P-type metal oxide-semiconductor logic **Input Circuit Pattern:** 8 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -30.0 volts power source **Time Rating Per Chacteristic:** 1000.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Rom **Test Data Document:** 24930-g390406 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:**

Fiig:

A458a0

Demilitarization: Yes - demil/mli